

MXene/Hybrid Composites	Initial Charge/Disc harge Capacity (mAh/g)	current density	CE (%)	Last capacity after cycling	Reference
Layered Ti ₃ C ₂ T _x	335	0.1 A/g	~100%	260 (1A/g)	Song et al. ¹
Functionalized activate titanium carbide nanorod growth on the surface of Ti ₃ C ₂ T _x (FTCN-MXene)	1133	0.1C	98.78	692 (3C)	Nam et al. ²
Ti ₃ C ₂ T _x /TiO ₂	272	0.5 C (50 mA/g)	-----	140 (after the 200 mA/g)	Liu et al. ³
Si/Ti ₃ C ₂	879	0.2A/g	69% initial CE	242 (3 A/g)	Kong et al. ⁴
Si@Ti ₃ C ₂	3502.3	0.1A/g	99.8%	1720.8 (1A/g)	Yang et al. ⁵
Ti ₃ C ₂ T _x /Si scrolls	226	100 mA/g	100%	89 (5000 mAh/g)	Meng et al. ⁶
Si/d-Ti ₃ C ₂	1948	0.2A/g	98% (after 7 th cycles)	890 (2 A/g)	Zhu et al. ⁷
SiO/Wrinkled MXene	1987	200 mA/g		713 (2000 mA/g)	Wei et al. ⁸
Binder free Si/MXene composites	2118	200 mA/g	71% (1st cycle)	1672(1000 mA/g)	Tian et al. ⁹
Si/Alg/MXene(80/16/4)	3800	0.1C	Initial CE 80%	1050 (1C)	Sarang et al. ¹⁰
Ti ₃ C ₂ T _x /Si	731	0.1 C	100 %	252 (after 200 cycles)	Li et al. ¹¹
SiNP@MX1/MX2	2865	0.05 A/g	100%	574 (5	Li et al. ¹²

				A/g)	
Si/Ti ₃ C ₂ T _x	1067.6	300 mA/g	----	648 (300 mA/g after 100 cycles	Zhang et al. ¹³
Ti ₃ C ₂ @Si/SiO _x @TiO ₂	1536	100mA/g	>98%	355 (2000 A/g)	Jiang et al. ¹⁴
SiO ₂ /MXene	840	0.1 A/g	99.99%(after 2 nd cycle)	517 (3A/g)	Mu et al. ¹⁵
Si p-NSs@TNs	1498	0.1 A/g	80.2 % (ICE)	899 (4 A/g)	Xia et al. ¹⁶
SiO ₂ /Ti ₃ C ₂	567	0.1 C	99.6	134.2 (5C)	Liu et al. ¹⁷
Si/d-Ti ₃ C ₂	1948	0.1 C	74% (ICE)	890 (2C)	Zhu et al. ⁷
Si@MXene capsules	1797	0.2 A/g	99.6%	759 (2 A/g)	Yan et al. ¹⁸
Ti ₃ C ₂ T _x /SnO ₂	1021	1C (100 mA/g)	98.5	500 (after 700 cycles)	Xiong et al. ¹⁹
SnO ₂ /MXene@200	843	500 mA/g	-----	514 (50 cycles)	Ahmed et al. ²⁰
10-SnO _x /Ti ₃ C ₂ T _x	729.1	50 mA/g	-----	581 (50 cycles)	Chen et al. ²¹
SnO ₂ /Ti ₃ C ₂	1030.1 mAh/g	1C	98%	82 mAh/g (5C)	Wang et al. ²²
SnO ₂ QDs@d-Ti ₃ C ₂ T _x	1046	0.5C	98%	350 (10 C)	Wang et al. ²³
PVP-Sn(IV)@ Ti ₃ C ₂	1637 mA/cm ³	50 mA/g	99%	698 mA/cm ³ (3000 mA/g)	Luo et al. ²⁴

Snnanocomplexpillared few layer Ti ₃ C ₂ T _x MXene (STCT)	881.5 mAh/g	500 mA/g	97.2%	662 (5000) mA/g	Zhang et al. ²⁵
3D Sn@ Ti ₃ C ₂	803mAh/g	0.1 A/g	> 99%	238 (3A/g)	Wang et al. ²⁶
0D–2D SnO ₂ QDs/MXene	887.5 mAh/g	50 mA/g	Close to 100%	364 (3000 mA/g)	Liu et al. ²⁷
SnO _x @Ti ₃ C ₂	365	0.1 A/g	99.9%	190 (2A/g)	Sun et al. ²⁸
Sn/SnO _x @Ti ₃ C ₂	834.5	50 mA/g	90.3 % (ICE)	Discharge capacity 194.5 (5 A/g)	Zuo et al. ²⁹
Porous-Ti ₃ C ₂ T _x CNT	1250	0.1 C	100	500 (after 100 cycles	Ren et al. ³⁰
Ti ₃ C ₂ /CNT/Fe/CF	430	1A/g	58.7	175 (10 A/g)	Zheng et al. ³¹
C-Fe ₃ O ₄ /Ti ₃ C ₂	1196.8	0.5 A/g	-	780 (2 A/g)	Li et al. ³²
Ti ₃ C ₂ T _x -CNTs/SiNPs	2583	100 mA/g	---	750 (1000 mA/g)	Cao et al. ³³
C@Si@CNTs-7.5	880	100 mA/g	99%	653 (1000 mA/g)	Yang et al. ³⁴
MXene/CNTs@P	2598	0.05	77%	454 (30 C)	Zhang et al. ³⁵
1:1 Ti ₃ C ₂ / rGO	473	0.05 A/g	---	16.7 (4A/g)	Ma et al. ³⁶
rGO/Ti ₂ CT _r	920	50 mA/g	>99%	300 (2000 mA/g)	Xu et al. ³⁷
Ti ₃ C ₂ /TiO ₂ /rGO	339	0.1 A/g	99%	173 (10 A/g)	Li et al. ³⁸
Ti3C2Tx-CNT/SiNPs	5.2 mAh/Cm ²	100 mA/g	62.8 % (ICE)	5.3 mAh/Cm ² (2000	Cao et al. ³⁹

				mA/g)	
T-MXene@C	499.4	0.2 C	56.9% (ICE)	101.5 (100 C)	Zhang et al. ⁴⁰
MXene/Si@SiOx@C-2	1674 mAh g ⁻¹	0.2 C	81.3% (ICE) after that 100%	510 (10 C)	Zhang et al. ⁴¹

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